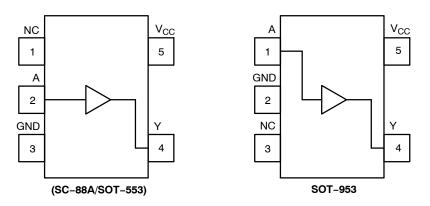
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Single Input Buffer MARKING DIAGRAMS **NLV17SZ16** SC-88A XX M= **DF SUFFIX** The NLV17SZ16 is a single input Buffer in tiny footprint packages. CASE 419A Features • Designed for 1.65 V to 5.5 V V_{CC} Operation SOT-553 • 2.4 ns t_{PD} at $V_{CC} = 5 V (typ)$ **XV5 SUFFIX** CASE 463B • Inputs/Outputs Overvoltage Tolerant up to 5.5 V • I_{OFF} Supports Partial Power Down Protection SOT-953 • Source/Sink 24 mA at 3.0 V **P5 SUFFIX** • Available in SC-88A, SOT-553 and SOT-953 Packages CASE 527AE • Chip Complexity < 100 FETs Specific Device Code • NLV Prefix for Automotive and Other Applications Requiring Date Code* м Unique Site and Control Change Requirements; AEC-Q100 = Pb-Free Package Qualified and PPAP Capable (Note: Microdot may be in either location) • These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS *Date Code orientation and/or position may Compliant vary depending upon manufacturing location. THIS DEFINITION OF CONVERSES NOT CONVERSES IN THIS DEFINITION OF CONVERSES IN THIS DEFINITION. ORDERING INFORMATION See detailed ordering, marking and shipping information on page 7 of this data sheet.

NLV17SZ16





PIN ASSIGNMENT

(SC-88A/SOT-553)

PIN ASSIGNMENT (SOT-953)

FUNCTION TABLE A Input

Y Output

L

н

Pin	Function	Pin	Function	A Input
1	NC	1	A	L
2	A	2	GND	Н
3	GND	3	NC	EV
4	Y	4	Y	RNI
5	V _{CC}	5	V _{CC}	N im 10:
THIS	DEVICE IS DEVICE PI RE	NOT RECON	MAENDEU ACT VOUR NEFOR IN	FORMEN

MAXIMUM RATINGS

Symbol	Characteristics		Value	Unit
V _{CC}	DC Supply Voltage		–0.5 to +7.0	V
V _{IN}	DC Input Voltage		–0.5 to +7.0	V
V _{OUT}		re-Mode (High or Low State) Tri-State Mode (Note 1) ver-Down Mode (V _{CC} = 0 V)	-0.5 to V _{CC} + 0.5 -0.5 to +7.0 -0.5 to +7.0	V
	DC Output Voltage (NL1	7SZ16P5T5G-L22088 Only)	–0.5 to V _{CC} + 0.5	
I _{IK}	DC Input Diode Current	V _{IN} < GND	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < GND	-50	mA
	DC Output Diode Current (NL1	7SZ16P5T5G-L22088 Only)	±50	
IOUT	DC Output Source/Sink Current		±50	mA
I _{CC} or I _{GND}	DC Supply Current per Supply Pin or Ground Pin	±100	mA	
T _{STG}	Storage Temperature Range	-65 to +150	7 ∘C	
ΤL	Lead Temperature, 1 mm from Case for 10 secs		260	°C
TJ	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 2)	SC-88A SOT-553 SOT-953	377 324 254	°C/W
PD	Power Dissipation in Still Air	SC-88A SOT-553 SOT-953	Semi 332 386 491	mW
MSL	Moisture Sensitivity	DE O	Level 1	-
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V_{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	V
I _{Latchup}	Latchup Performance (Note 4)	A A	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
Applicable to devices with outputs that may be tri-stated.
Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
Tested to EIA/JESD78 Class II.

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THIS DEV

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics			Max	Unit
V _{CC}	Positive DC Supply Voltage		1.65	5.5	V
V _{IN}	DC Input Voltage		0	5.5	V
V _{OUT}	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V _{CC} = 0 V)	0 0 0	V _{CC} 5.5 5.5	V
	DC Output Voltage	(NL17SZ16P5T5G-L22088 Only)	0	V _{CC}	
T _A	Operating Temperature Range		-55	+125	°C
t _r , t _f	Input Rise and Fall Time	V _{CC} = 3.0 V to 3.6 V V _{CC} = 4.5 V to 5.5 V	0 0	100 20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

			V _{cc}	$T_A = 25^{\circ}C$ $-55^{\circ}C =$		–55°C ≤ T _A ≤ 125°C			
Symbol	Parameter	Condition	(V)	Min	Тур	Мах	Min	Max	Units
VIH	High-Level Input		1.65 to 1.95	0.75 x V _{CC}			0.75 x V _{CC}		V
	Voltage		2.3 to 5.5	0.70 x V _{CC}		N	0.70 x V _{CC}		
V_{IL}	Low-Level Input		1.65 to 1.95			0.25 x V _{CC}		0.25 x V _{CC}	V
	Voltage		2.3 to 5.5		JY.	0.30 x V _{CC}	1014	0.30 x V _{CC}	
V _{OH}	High-Level Output Voltage		1.65 to 5,5 1.65 2.3 2,7 3,0 3.0 4,5	V _{CC} = 0.1 1.29 1.9 2.2 2.4 2.3 3.8	V _{CC} 1.4 2.1 2.4 2.7 2.5 4.0	ORINA	V _{CC} - 0.1 1.29 1.9 2.2 2.4 2.3 3.8		V
V _{OL}	Low-Level Output Voltage		1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5		- 0.08 0.2 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55		0.1 0.24 0.3 0.4 0.4 0.55 0.55	V
I _{IN}	Input Leakage Current	V _{IN} = 5.5 V or GND	1.65 to 5.5	-	-	±0.1	-	±1.0	μA
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5 V or V _{OUT} = 5.5 V	0	-	-	1.0	-	10	μA
	Power Off Leakage Current (NL17SZ16P5T5G- L22088 Only)	V _{IN} = 5.5 V	0	_	-	1.0	_	10	μΑ
ICC	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5	-	-	1.0	_	10	μA

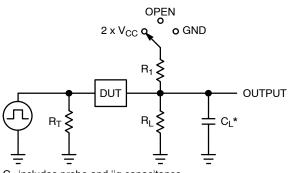
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

			v _{cc}	T,	д = 25°	С	–55°C ≤ T	_A ≤ 125°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units
t _{PLH}	Propagation Delay, A to Y	R_L = 1 MΩ, C_L = 15 pF	1.65 to 1.95	-	5.3	11.4	-	12.0	ns
τρηΓ	t _{PHL} (Figures 3 and 4)	R_L = 1 MΩ, C_L = 15 pF	2.3 to 2.7	-	2.9	6.5	-	7.0	
		$R_L = 1 M\Omega$, $C_L = 15 pF$	3.0 to 3.6	_	2.1	4.5	-	4.7	
		$R_L = 500 \Omega$, $C_L = 50 pF$		_	2.9	5.0	-	5.2	
		$R_L = 1 M\Omega$, $C_L = 15 pF$	4.5 to 5.5	_	1.8	3.9	-	4.1	
		$R_L = 500 \Omega$, $C_L = 50 pF$		_	2.4	4.3	-	4.5	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Units
C _{IN}	Input Capacitance	V_{CC} = 5.5 V, V_{IN} = 0 V or V_{CC}	2.5	pF
C _{OUT}	Output Capacitance	V_{CC} = 5.5 V, V_{IN} = 0 V or V_{CC}	2.5	pF
C _{PD}	Power Dissipation Capacitance (Note 5)	10 MHz, V_{CC} = 3.3 V, V_{IN} = 0 V or V_{CC} 10 MHz, V_{CC} = 5.5 V, V_{IN} = 0 V or V_{CC}	9 11	pF
Average power c		lent capacitance which is calculated from the operating current consule e equation: I _{CC(OPR)} = C _{PD} • V _{CC} • I _{in} + I _{CC} . C _{PD} is used to determine • V _{CC} .		out lo

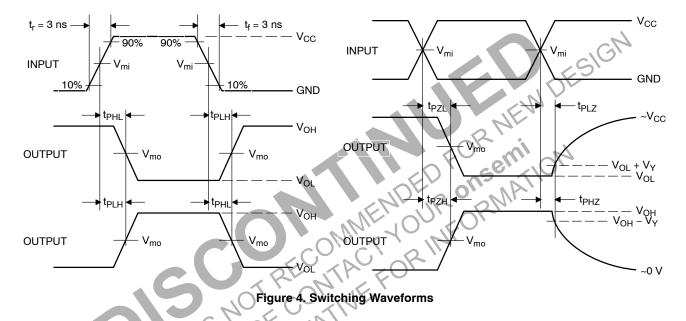


Switch R_1, Ω Test C_L, pF R_L, Ω Position t_{PLH} / t_{PHL} Open See AC Characteristics Table 50 500 $2 \times V_{CC}$ 500 t_{PLZ} / t_{PZL} GND 50 500 500 t_{PHZ} / t_{PZH}

X = Don't Care

 C_L includes probe and jig capacitance R_T is Z_{OUT} of pulse generator (typically 50 $\Omega)$ f = 1 MHz

Figure 3. Test Circuit



	NCENERGE	V _m	_o , V	
V _{CC} , V	V _{mi} , V	t _{PLH} , t _{PHL}	t _{PZL} , t _{PLZ} , t _{PZH} , t _{PHZ}	V _Y , V
1.65 to 1.95	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.15
2.3 to 2.7	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.15
3.0 to 3.6	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.3
4.5 to 5.5	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.3

NLV17SZ16

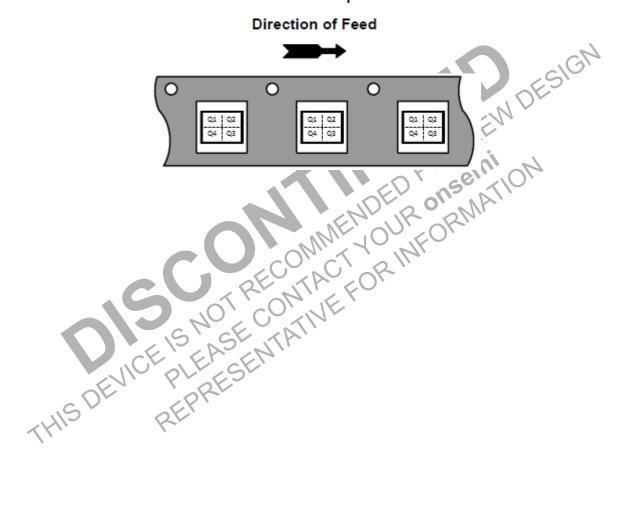
DEVICE ORDERING INFORMATION

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping [†]
NL17SZ16DFT2G-L22038	SC-88A	LR	Q4	3000 / Tape & Reel
NL17SZ16XV5T2G-L22087	SOT-553	LR	Q4	4000 / Tape & Reel
NL17SZ16P5T5G-L22088	SOT-953	L (Rotated 180°)	Q2	8000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

Pin 1 Orientation in Tape and Reel



NSEM



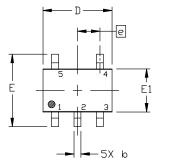
SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE M**

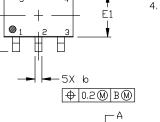
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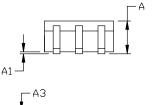
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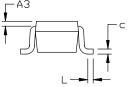
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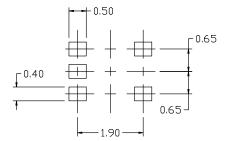
DATE 11 APR 2023











RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS				
MIU	MIN.	NDM.	MAX.		
A	0.80	0.95	1.10		
A1			0.10		
A3	0.20 REF				
b	0.10	0.20	0.30		
С	0.10		0.25		
D	1.80	2.00	5'50		
E	2.00	2.10	5'50		
E1	1.15	1.25	1.35		
e	0.65 BSC				
L	0.10	0.15	0.30		

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSOLETE, NEW STANDARD 419A-02

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

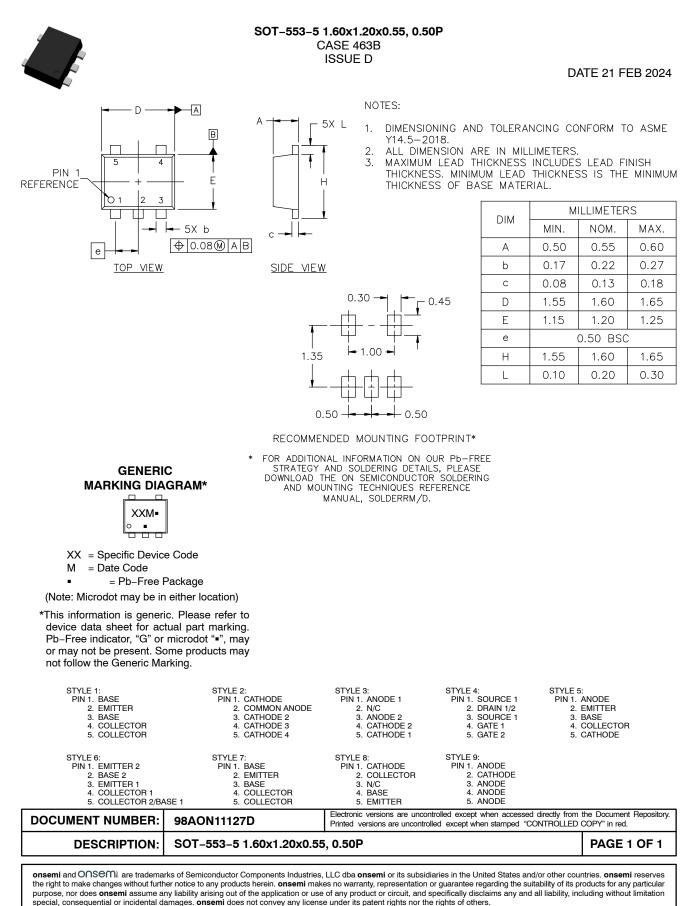
(Note: Microdot may be in either location)

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANOD 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	E	
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to style callout. If style to out in the datasheet r datasheet pinout or p	ype is not called efer to the device	
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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



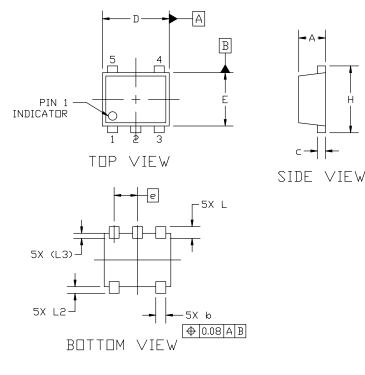
SOT-953 1.00x0.80x0.37, 0.35P CASE 527AE ISSUE F

DATE 17 JAN 2024

DURSEM

NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- 2. CONTROLLING DIMENSION: MILLIMETERS,
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS DF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.



GENERIC MARKING DIAGRAM*

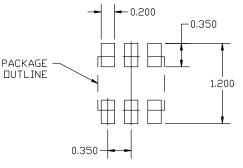


- X = Specific Device Code M = Month Code
- *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	SOT-953 1.00x0.80x0.37, 0.35P		PAGE 1 OF 8	
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3,	MILLIMETERS				
	DIM	MIN	NDM	MAX	
	А	0.34	0.37	0.40	
	Q	0.10	0,15	0.20	
	С	0.07	0.12	0.17	
	D	0.95	1.00	1.05	
	E	0.75	0.80	0.85	
	e	().35 BSC	2	
	I	0.95	1.00	1.05	
		0.125	0.175	0.225	
	L2	0.05	0.10	0.15	
	L3	0.075 (REF)			



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

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